NSN 5962-01-313-6149

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-313-6149

Body Length:

1.280 inches

Body Width:

Between 0.220 inches and 0.310 inches

Body Height:

Between 0.140 inches and 0.185 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Asynchronous and w/clock and programmed and erasable and w/enable and w/disable and bidirectional

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Case Outline Source And Designator:

D-9 mil-m-38510

Current Rating Per Characteristic:

60.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

600 gate epld

Voltage Rating And Type Per Characteristic:

-2.0 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

20.00 input picofarads and 20.00 output picofarads

Time Rating Per Chacteristic:

55.00 nanoseconds access

Memory Device Type:

Pal

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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